NSN 5961-00-103-1669

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View Online at https://aerobasegroup.com/nsn/5961-00-103-1669 **Inclosure Material:** Plastic **Overall Length:** 0.890 inches **Overall Height:** 0.160 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Overall Width Across Flats:** 0.460 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current and 12.00 amperes source cutoff current **Power Rating Per Characteristic:** 83.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: